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SEMICONDUCTOR

CD4013BC Dual D-Type Flip-Flop

General Description

The CD4013B dual D-type flip-flop is a monolithic complementary MOS (CMOS) integrated circuit constructed with N- and P-channel enhancement mode transistors. Each flip-flop has independent data, set, reset, and clock inputs and "Q" and "Q" outputs. These devices can be used for shift register applications, and by connecting "Q" output to the data input, for counter and toggle applications. The logic level present at the "D" input is transferred to the Q output during the positive-going transition of the clock pulse. Setting or resetting is independent of the clock and is accomplished by a high level on the set or reset line respectively.

Features

■ Wide supply voltage range: 3.0V to 15V

- High noise immunity: 0.45 V_{DD} (typ.)
- Low power TTL: fan out of 2 driving 74L compatibility: or 1 driving 74LS

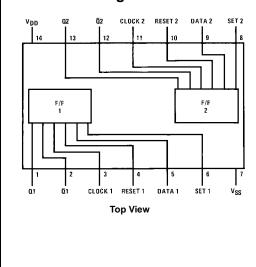
Applications

- Automotive
- Data terminals
- Instrumentation
- Medical electronics
- Alarm system
- Industrial electronics
- Remote metering
- Computers

Ordering Code:

Order Number Package Number		Package Description	
CD4013BCM M14A 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow			
CD4013BCSJ M14D 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide			
CD4013BCN N14A 14-Lead Plastic Dual-In-Line Pac		14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide	
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.			

Connection Diagram



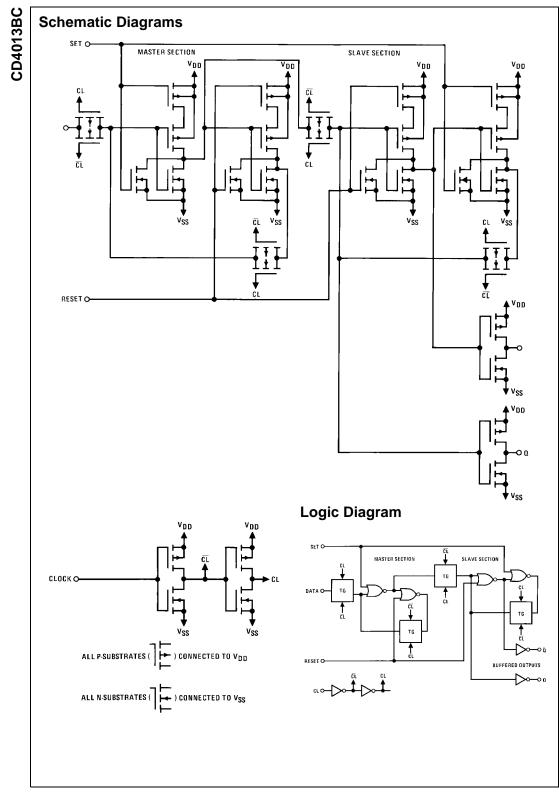
Truth Table

	CL (Note 1)	D	R	S	Q	Q
	\langle	0	0	0	0	1
	~	1	0	0	1	0
	~	х	0	0	Q	Q
	х	х	1	0	0	1
	х	х	0	1	1	0
	x	х	1	1	1	1
No	No Change					

x = Don't Care Case

Note 1: Level Change

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Absolute Maximum Ratings(Note 2)

(Note 3)	
DC Supply Voltage (V _{DD})	–0.5 V_{DC} to +18 V_{DC}
Input Voltage (V _{IN})	–0.5 V_{DC} to V_{DD} +0.5 V_{DC}
Storage Temperature Range (T_S)	-65°C to +150°C
Power Dissipation (P _D)	
Dual-In-Line	700 mW
Small Outline	500 mW
Lead Temperature (T _L)	
(Soldering, 10 seconds)	260°C

Recommended Operating

Conditions (Note 3)

DC Supply Voltage (V_{DD}) Input Voltage (VIN)

0 V_{DC} to V_{DD} V_{DC}

+3 V_{DC} to +15 V_{DC}

Units

μΑ

v

v

v

v

mΑ

mΑ

μΑ

CD4013BC

-55°C to +125°C Operating Temperature Range (T_A) Note 2: "Absolute Maximum Ratings" are those values beyond which the

safety of the device cannot be guaranteed, they are not meant to imply that the devices should be operated at these limits. The tables of "Recom-

mended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.

Note 3: $V_{SS} = 0V$ unless otherwise specified.

–55°C +25°C +125°C Parameter Conditions Min Min Max Min Тур Max Max $V_{DD} = 5V, V_{IN} = V_{DD} \text{ or } V_{SS}$ Quiescent Device 1.0 1.0 30 $V_{DD} = 10V, V_{IN} = V_{DD} \text{ or } V_{SS}$ Current 2.0 2.0 60 $V_{DD} = 15V$, $V_{IN} = V_{DD}$ or V_{SS} 4.0 4.0 120 LOW Level |I_O| < 1.0 μA $V_{DD} = 5V$ Output Voltage 0.05 0.05 0.05 $V_{DD} = 10V$ 0.05 0.05 0.05 $V_{DD} = 15V$ 0.05 0.05 0.05 HIGH Level |I_O| < 1.0 μA Output Voltage $V_{DD} = 5V$ 4 95 4 95 4 95 $V_{DD} = 10V$ 9.95 9.95 9.95 $V_{DD} = 15V$ 14.95 14.95 14.95 LOW Level |I_O| < 1.0 μA Input Voltage $V_{DD}=5V,\,V_O=0.5V$ or 4.5V1.5 1.5 1.5 $V_{DD} = 10V, V_O = 1.0V \text{ or } 9.0V$ 3.0 3.0 3.0 $V_{DD} = 15V, V_{O} = 1.5V \text{ or } 13.5V$ 4.0 4.0 4.0 |I_O| < 1.0 μA HIGH Level Input Voltage $V_{DD}=5V,\,V_{O}=0.5V$ or 4.5V3.5 3.5 3.5 V_{DD} = 10V, V_{O} = 1.0V or 9.0V 7.0 7.0 7.0 $V_{DD} = 15 V, \, V_O = 1.5 V \text{ or } 13.5 V$ 11.0 11.0 11.0 LOW Level Output $V_{DD} = 5V, V_{O} = 0.4V$ 0.64 0.51 0.88 0.36 $V_{DD} = 10V, V_{O} = 0.5V$ Current (Note 4) 2.25 0.9

1.6

4.2

-0.64

-1.6

-4.2

-0.1

0.1

V_{DD} = 15V, V_O = 1.5V

 $V_{DD} = 5V, V_{O} = 4.6V$

 $V_{DD} = 10V, V_{O} = 9.5V$

 $V_{DD} = 15V, V_O = 13.5V$

 $V_{DD} = 15V, V_{IN} = 0V$

 $V_{DD} = 15V, V_{IN} = 15V$

1.3

3.4

-0.51

-1.3

-3.4

8.8

-0.88

-2 25

-8.8

-10⁻⁵

10⁻⁵

-0.1

0.1

2.4

-0.36

-0.9

-2.4

-1.0

1.0

DC Electrical Characteristics (Note 3)

Symbol

 I_{DD}

VOL

V_{он}

VIL

VIH

I_{OL}

I_{OH}

I_{IN}

HIGH Level Output

Note 4: I_{OH} and I_{OL} are measured one output at a time.

Current (Note 4)

Input Current

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AC Electrical Characteristics (Note 5)

Symbol

4	Cymbol
Ď	CLOCK OPERATION

t_{PHL}, t_{PLH}

$T_A = 25^{\circ}C, \ C_L = 50^{\circ}C$	$P pF, R_L = 200k$, unless otherwise noted	
Symbol	Parameter	Ī

Propagation Delay Time	$V_{DD} = 5V$
	$V_{DD} = 10V$
	$V_{DD} = 15V$
Transition Time	$V_{PP} = 5V$

t _{THL} , t _{TLH}	Transition Time	$V_{DD} = 5V$		100	200	
		$V_{DD} = 10V$		50	100	ns
		$V_{DD} = 15V$		40	80	
t _{WL} , t _{WH}	Minimum Clock	$V_{DD} = 5V$		100	200	
	Pulse Width	$V_{DD} = 10V$		40	80	ns
		$V_{DD} = 15V$		32	65	
t _{RCL} , t _{FCL}	Maximum Clock Rise and	$V_{DD} = 5V$			15	
	Fall Time	$V_{DD} = 10V$			10	μs
		$V_{DD} = 15V$			5	
t _{SU}	Minimum Set-Up Time	$V_{DD} = 5V$		20	40	
		$V_{DD} = 10V$		15	30	ns
		$V_{DD} = 15V$		12	25	
f _{CL}	Maximum Clock	$V_{DD} = 5V$	2.5	5		
	Frequency	$V_{DD} = 10V$	6.2	12.5		MHz
		$V_{DD} = 15V$	7.6	15.5		
SET AND RES	ET OPERATION					
t _{PHL(R)} ,	Propagation Delay Time	$V_{DD} = 5V$		150	300	
t _{PLH(S)}		$V_{DD} = 10V$		65	130	ns
		$V_{DD} = 15V$		45	90	
t _{WH(R)} ,	Minimum Set and	$V_{DD} = 5V$	l	90	180	
t _{WH(S)}	Reset Pulse Width	$V_{DD} = 10V$		40	80	ns
		$V_{DD} = 15V$		25	50	
CIN	Average Input Capacitance	Any Input		5	7.5	pF

Conditions

Min

Тур

200

80

65

Max

350

160

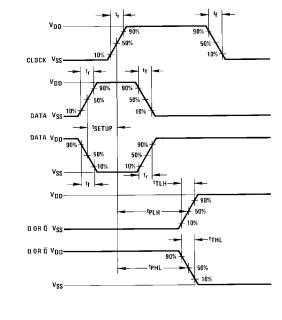
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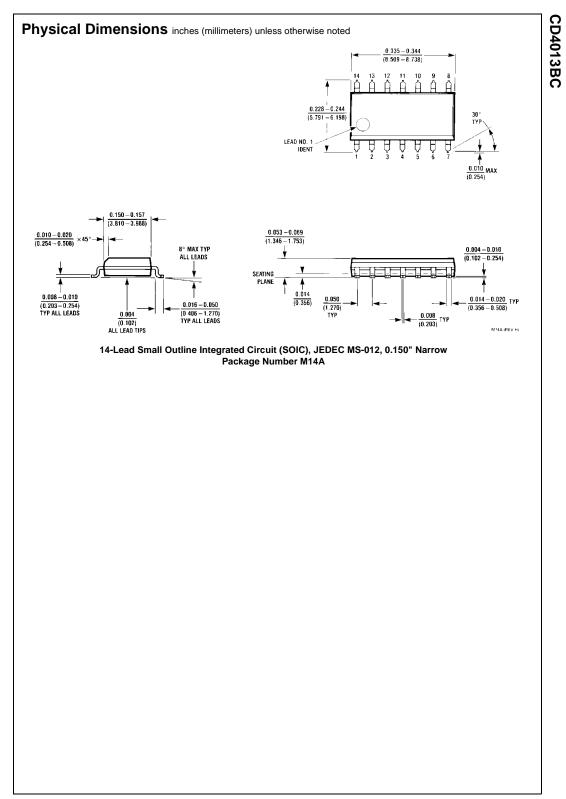
Units

ns

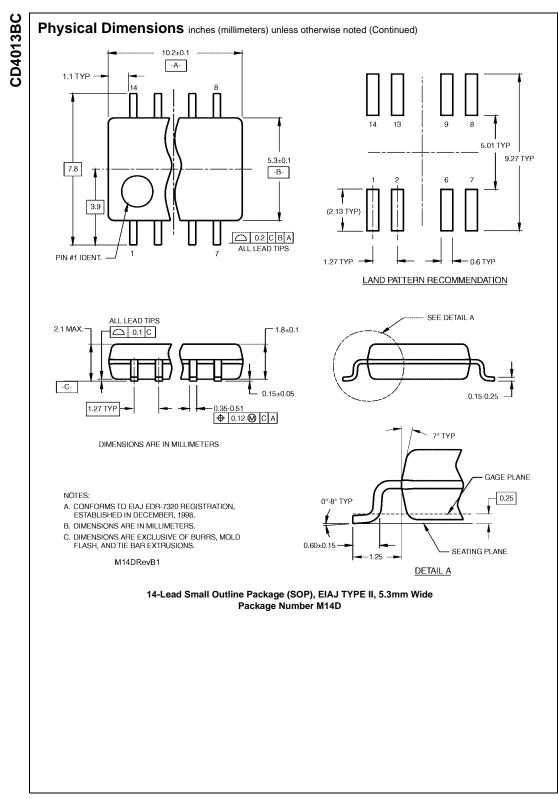
Note 5: AC Parameters are guaranteed by DC correlated testing.

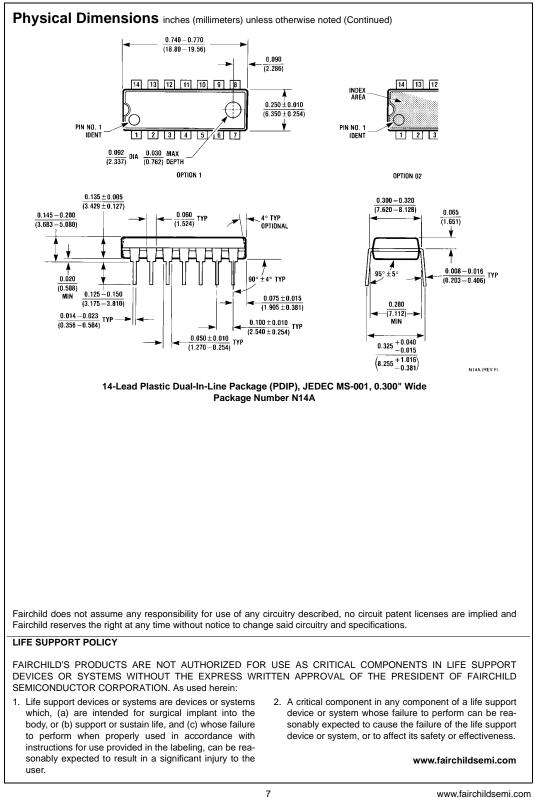
Switching Time Waveforms





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